

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Hattangady et al.

Art Unit:

2815

Serial No .:

10/783,081

Examiner:

Richards, N.

Filing Date:

02/19/2004

Docket No.:

TI-31017.1

Customer No.: 23494

6261

Conf. No.:

Title:

SEMICONDUCTOR WITH A NITRIDED SILICON GATE OXIDE

AND METHOD

REQUEST FOR EXTENSION OF TIME

Commissioner of Patents PO Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by faceimile to the U.S. Patent and Trademark Office at 703-872-9306 on

fhe date≪ own below.

Jacqueline J. Garner, Reg. No. 36,144

May 24, 2005 Date

Pursuant to 37 CFR 1.136(a), Applicant(s) respectfully petitions the Commissioner for an extension of the shortened statutory period for response in the above-identified

The fee for this extension is indicated below:

☐ One Month (\$120)

☐ Two Months (\$450)

☐ Four Months (\$1,590)

Please charge the fee to deposit account no. 20-0668. Any further necessary extension of time is hereby requested. Charge any and all fees to deposit account no. 20-0668.

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Respectfully Submitted,

Jacqueline J. Garner Reg. No. 36,144

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